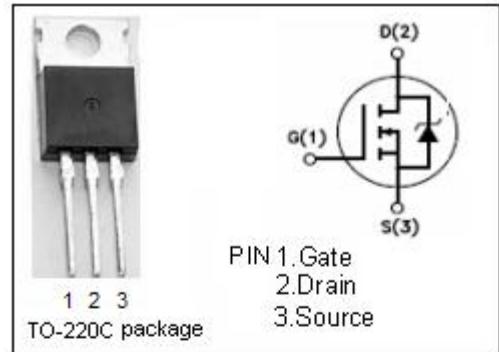


isc N-Channel MOSFET Transistor

2SK1876

DESCRIPTION

- Drain Current $I_D = 10A @ T_c=25^\circ C$
- Drain Source Voltage : $V_{DSS} = 450V$ (Min)
- Fast Switching Speed
- Low on-resistance
- For switching regulator,DC-DC Converter
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

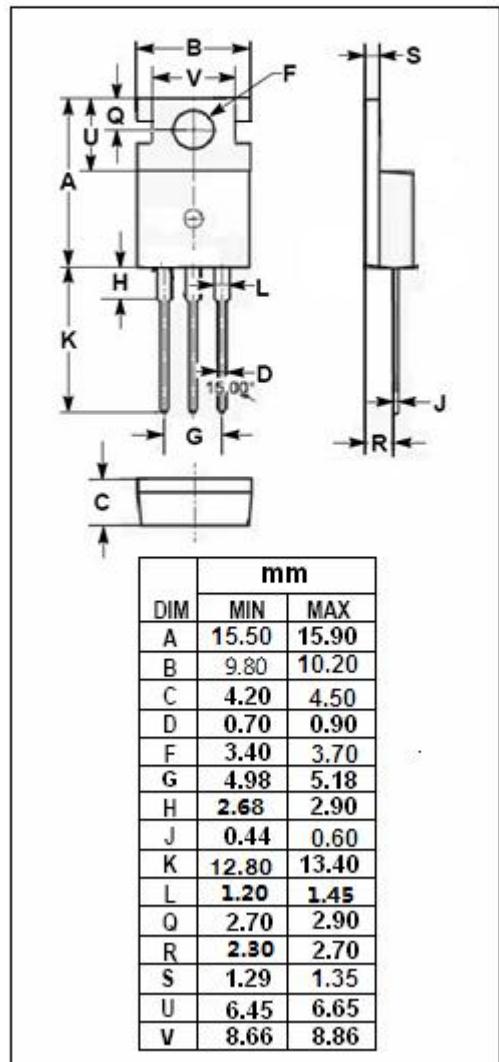
- High speed power switching

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage ($V_{GS}=0$)	450	V
V_{GS}	Gate-Source Voltage	± 30	V
I_D	Drain Current-continuous@ $T_C=25^\circ C$	10	A
P_{tot}	Total Dissipation@ $T_C=25^\circ C$	80	W
T_j	Max. Operating Junction Temperature	150	°C
T_{stg}	Storage Temperature Range	-55~150	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance, Junction to Case	1.56	°C/W
$R_{th j-a}$	Thermal Resistance, Junction to Ambient	75	°C/W



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• ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
$V_{(\text{BR})\text{DSS}}$	Drain-Source Breakdown Voltage	$V_{\text{GS}}= 0$; $I_D= 1\text{mA}$	450			V
$V_{(\text{BR})\text{GSS}}$	Gate-Source Breakdown Voltage	$V_{\text{DS}}= 0$; $I_G= 100 \mu\text{A}$	± 30			V
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}}= V_{\text{GS}}$; $I_D=1\text{mA}$	2.5		3.5	V
V_{DF}	Body to drain diode forward voltage	$I_S= 5\text{A}$, $V_{\text{GS}}= 0$		0.9		V
$R_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	$V_{\text{GS}}= 10\text{V}$; $I_D=5\text{A}$			0.65	Ω
I_{GSS}	Gate-Body Leakage Current	$V_{\text{GS}}= \pm 30\text{V}$; $V_{\text{DS}}= 0$			± 100	nA
I_{DSS}	Zero Gate Voltage Drain Current	$V_{\text{DS}}=450\text{V}$; $V_{\text{GS}}= 0$			500	μA
C_{iss}	Input Capacitance	$V_{\text{DS}}=10\text{V}$; $V_{\text{GS}}=0\text{V}$; $f_T=1\text{MHz}$		1800		pF
C_{rss}	Reverse Transfer Capacitance			100		
C_{oss}	Output Capacitance			240		
t_r	Rise Time	$V_{\text{GS}}=10\text{V}$; $I_D=2.5\text{A}$; $V_{\text{DD}}=200\text{V}$; $R_L=12\Omega$		120		ns
t_{on}	Turn-on Time			45		
t_f	Fall Time			120		
t_{off}	Turn-off Time			240		

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